NSN 5961-01-192-4433

Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-192-4433 **Inclosure Material:** Glass **Overall Length:** 0.300 inches **Terminal Length:** 0.975 inches **Overall Diameter:** 0.145 inches **End Application:** 6605-01-141-0857 **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 400.0 reverse voltage, peak **Current Rating Per Characteristic:** 3.00 amperes base current, instantaneous megahertz and 20.00 amperes forward current, average pascal **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: No